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#### Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

#### Applications of **Embedded - Microprocessors**

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

#### Details

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# 2 Features

The following list summarizes the key MPC860 features:

- Embedded single-issue, 32-bit core (implementing the Power Architecture technology) with thirty-two 32-bit general-purpose registers (GPRs)
  - The core performs branch prediction with conditional prefetch without conditional execution.
  - 4- or 8-Kbyte data cache and 4- or 16-Kbyte instruction cache (see Table 1)
    - 16-Kbyte instruction caches are four-way, set-associative with 256 sets; 4-Kbyte instruction caches are two-way, set-associative with 128 sets.
    - 8-Kbyte data caches are two-way, set-associative with 256 sets; 4-Kbyte data caches are two-way, set-associative with 128 sets.
    - Cache coherency for both instruction and data caches is maintained on 128-bit (4-word) cache blocks.
    - Caches are physically addressed, implement a least recently used (LRU) replacement algorithm, and are lockable on a cache block basis.
  - MMUs with 32-entry TLB, fully-associative instruction, and data TLBs
  - MMUs support multiple page sizes of 4-, 16-, and 512-Kbytes, and 8-Mbytes; 16 virtual address spaces and 16 protection groups
  - Advanced on-chip-emulation debug mode
- Up to 32-bit data bus (dynamic bus sizing for 8, 16, and 32 bits)
- 32 address lines
- Operates at up to 80 MHz
- Memory controller (eight banks)
  - Contains complete dynamic RAM (DRAM) controller
  - Each bank can be a chip select or  $\overline{RAS}$  to support a DRAM bank.
  - Up to 15 wait states programmable per memory bank
  - Glueless interface to DRAM, SIMMS, SRAM, EPROM, Flash EPROM, and other memory devices
  - DRAM controller programmable to support most size and speed memory interfaces
  - Four  $\overline{\text{CAS}}$  lines, four  $\overline{\text{WE}}$  lines, and one  $\overline{\text{OE}}$  line
  - Boot chip-select available at reset (options for 8-, 16-, or 32-bit memory)
  - Variable block sizes (32 Kbytes to 256 Mbytes)
  - Selectable write protection
  - On-chip bus arbitration logic
- General-purpose timers
  - Four 16-bit timers or two 32-bit timers
  - Gate mode can enable/disable counting
  - Interrupt can be masked on reference match and event capture.



**Thermal Calculation and Measurement** 

# 7 Thermal Calculation and Measurement

For the following discussions,  $P_D = (V_{DD} \times I_{DD}) + PI/O$ , where PI/O is the power dissipation of the I/O drivers.

# 7.1 Estimation with Junction-to-Ambient Thermal Resistance

An estimation of the chip junction temperature, T<sub>J</sub>, in °C can be obtained from the equation:

$$T_J = T_A + (R_{\theta JA} \times P_D)$$

where:

 $T_A$  = ambient temperature (°C)

 $R_{\theta JA}$  = package junction-to-ambient thermal resistance (°C/W)

 $P_D$  = power dissipation in package

The junction-to-ambient thermal resistance is an industry standard value which provides a quick and easy estimation of thermal performance. However, the answer is only an estimate; test cases have demonstrated that errors of a factor of two (in the quantity  $T_J - T_A$ ) are possible.

# 7.2 Estimation with Junction-to-Case Thermal Resistance

Historically, the thermal resistance has frequently been expressed as the sum of a junction-to-case thermal resistance and a case-to-ambient thermal resistance:

 $R_{\theta JA} = R_{\theta JC} + R_{\theta CA}$ 

where:

 $R_{\theta JA}$  = junction-to-ambient thermal resistance (°C/W)

 $R_{\theta IC}$  = junction-to-case thermal resistance (°C/W)

 $R_{\theta CA}$  = case-to-ambient thermal resistance (°C/W)

 $R_{\theta JC}$  is device related and cannot be influenced by the user. The user adjusts the thermal environment to affect the case-to-ambient thermal resistance,  $R_{\theta CA}$ . For instance, the user can change the airflow around the device, add a heat sink, change the mounting arrangement on the printed-circuit board, or change the thermal dissipation on the printed-circuit board surrounding the device. This thermal model is most useful for ceramic packages with heat sinks where some 90% of the heat flows through the case and the heat sink to the ambient environment. For most packages, a better model is required.

# 7.3 Estimation with Junction-to-Board Thermal Resistance

A simple package thermal model which has demonstrated reasonable accuracy (about 20%) is a two-resistor model consisting of a junction-to-board and a junction-to-case thermal resistance. The junction-to-case thermal resistance covers the situation where a heat sink is used or where a substantial amount of heat is dissipated from the top of the package. The junction-to-board thermal resistance describes the thermal performance when most of the heat is conducted to the printed-circuit board. It has been observed that the thermal performance of most plastic packages, especially PBGA packages, is strongly dependent on the board temperature; see Figure 2.



	Obeve et eviet i -	33 MHz		40 MHz		50 MHz		66 MHz		
Num	Characteristic	Min	Мах	Min	Max	Min	Мах	Min	Max	Unit
B23	CLKOUT rising edge to $\overline{CS}$ negated GPCM read access, GPCM write access ACS = 00, TRLX = 0, and CSNT = 0	2.00	8.00	2.00	8.00	2.00	8.00	2.00	8.00	ns
B24	A(0:31) and BADDR(28:30) to $\overline{CS}$ asserted GPCM ACS = 10, TRLX = 0	5.58	—	4.25	_	3.00	_	1.79	—	ns
B24a	A(0:31) and BADDR(28:30) to $\overline{CS}$ asserted GPCM ACS = 11, TRLX = 0	13.15	—	10.50	—	8.00	—	5.58	—	ns
B25	CLKOUT rising edge to $\overline{OE}$ , $\overline{WE}$ (0:3) asserted	—	9.00	—	9.00	—	9.00	—	9.00	ns
B26	CLKOUT rising edge to OE negated	2.00	9.00	2.00	9.00	2.00	9.00	2.00	9.00	ns
B27	A(0:31) and BADDR(28:30) to $\overline{CS}$ asserted GPCM ACS = 10, TRLX = 1	35.88	_	29.25	_	23.00	_	16.94	_	ns
B27a	A(0:31) and BADDR(28:30) to $\overline{CS}$ asserted GPCM ACS = 11, TRLX = 1	43.45	—	35.50	—	28.00	—	20.73	—	ns
B28	CLKOUT rising edge to $\overline{WE}(0:3)$ negated GPCM write access CSNT = 0	—	9.00	—	9.00	—	9.00	—	9.00	ns
B28a	CLKOUT falling edge to $\overline{WE}(0:3)$ negated GPCM write access TRLX = 0, 1, CSNT = 1, EBDF = 0	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.54	ns
B28b	CLKOUT falling edge to $\overline{CS}$ negated GPCM write access TRLX = 0, 1, CSNT = 1, ACS = 10, or ACS = 11, EBDF = 0	—	14.33	—	13.00		11.75		10.54	ns
B28c	CLKOUT falling edge to $\overline{WE}$ (0:3) negated GPCM write access TRLX = 0, 1, CSNT = 1 write access TRLX = 0, CSNT = 1, EBDF = 1	10.86	17.99	8.88	16.00	7.00	14.13	5.18	12.31	ns
B28d	CLKOUT falling edge to $\overline{CS}$ negated GPCM write access TRLX = 0, 1, CSNT = 1, ACS = 10, or ACS = 11, EBDF = 1	_	17.99	_	16.00		14.13		12.31	ns
B29	$\overline{WE}(0:3)$ negated to D(0:31), DP(0:3) High-Z GPCM write access CSNT = 0, EBDF = 0	5.58	_	4.25	—	3.00	—	1.79	—	ns
B29a	$\overline{WE}(0:3)$ negated to D(0:31), DP(0:3) High-Z GPCM write access, TRLX = 0, CSNT = 1, EBDF = 0	13.15	—	10.5	—	8.00		5.58	—	ns
B29b	$\overline{\text{CS}}$ negated to D(0:31), DP(0:3), High-Z GPCM write access, ACS = 00, TRLX = 0, 1, and CSNT = 0	5.58		4.25		3.00		1.79		ns
B29c	$\overline{\text{CS}}$ negated to D(0:31), DP(0:3) High-Z GPCM write access, TRLX = 0, CSNT = 1, ACS = 10, or ACS = 11, EBDF = 0	13.15		10.5		8.00		5.58		ns

# Table 7. Bus Operation Timings (continued)



	Ohannatariistia	33 MHz		40 MHz		50 MHz		66 MHz		
Num	Characteristic	Min	Max	Min	Max	Min	Max	Min	Max	Unit
B31a	CLKOUT falling edge to CS valid—as requested by control bit CST1 in the corresponding word in UPM	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.54	ns
B31b	CLKOUT rising edge to $\overline{CS}$ valid—as requested by control bit CST2 in the corresponding word in UPM	1.50	8.00	1.50	8.00	1.50	8.00	1.50	8.00	ns
B31c	CLKOUT rising edge to $\overline{\text{CS}}$ valid—as requested by control bit CST3 in the corresponding word in UPM	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.04	ns
B31d	CLKOUT falling edge to $\overline{CS}$ valid—as requested by control bit CST1 in the corresponding word in UPM, EBDF = 1	13.26	17.99	11.28	16.00	9.40	14.13	7.58	12.31	ns
B32	CLKOUT falling edge to BS valid—as requested by control bit BST4 in the corresponding word in UPM	1.50	6.00	1.50	6.00	1.50	6.00	1.50	6.00	ns
B32a	CLKOUT falling edge to $\overline{BS}$ valid—as requested by control bit BST1 in the corresponding word in UPM, EBDF = 0	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.54	ns
B32b	CLKOUT rising edge to $\overline{\text{BS}}$ valid—as requested by control bit BST2 in the corresponding word in UPM	1.50	8.00	1.50	8.00	1.50	8.00	1.50	8.00	ns
B32c	CLKOUT rising edge to $\overline{\text{BS}}$ valid—as requested by control bit BST3 in the corresponding word in UPM	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.54	ns
B32d	CLKOUT falling edge to $\overline{BS}$ valid—as requested by control bit BST1 in the corresponding word in UPM, EBDF = 1	13.26	17.99	11.28	16.00	9.40	14.13	7.58	12.31	ns
B33	CLKOUT falling edge to GPL valid—as requested by control bit GxT4 in the corresponding word in UPM	1.50	6.00	1.50	6.00	1.50	6.00	1.50	6.00	ns
B33a	CLKOUT rising edge to GPL valid—as requested by control bit GxT3 in the corresponding word in UPM	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.54	ns
B34	A(0:31), BADDR(28:30), and D(0:31) to $\overline{CS}$ valid—as requested by control bit CST4 in the corresponding word in UPM	5.58	—	4.25	—	3.00	—	1.79	_	ns
B34a	A(0:31), BADDR(28:30), and D(0:31) to $\overline{CS}$ valid—as requested by control bit CST1 in the corresponding word in UPM	13.15		10.50		8.00		5.58	_	ns
B34b	A(0:31), BADDR(28:30), and D(0:31) to $\overline{CS}$ valid—as requested by control bit CST2 in the corresponding word in UPM	20.73	_	16.75	_	13.00		9.36	_	ns

# Table 7. Bus Operation Timings (continued)



Figure 3 is the control timing diagram.



Figure 4 provides the timing for the external clock.



Figure 4. External Clock Timing



**Bus Signal Timing** 

Figure 5 provides the timing for the synchronous output signals.



Figure 5. Synchronous Output Signals Timing

Figure 6 provides the timing for the synchronous active pull-up and open-drain output signals.



Figure 6. Synchronous Active Pull-Up Resistor and Open-Drain Outputs Signals Timing





Figure 7 provides the timing for the synchronous input signals.



Figure 8 provides normal case timing for input data. It also applies to normal read accesses under the control of the UPM in the memory controller.



Figure 8. Input Data Timing in Normal Case



Figure 14 through Figure 16 provide the timing for the external bus write controlled by various GPCM factors.



Figure 14. External Bus Write Timing (GPCM Controlled—TRLX = 0 or 1, CSNT = 0)



Bus Signal Timing

# Table 9 shows the PCMCIA timing for the MPC860.

Table 9. PCMCIA Timing

Num	Characteristic	33 MHz		40 MHz		50 MHz		66 MHz		11
Num		Min	Max	Min	Max	Min	Max	Min	Max	Unit
P44	A(0:31), REG valid to PCMCIA Strobe asserted <sup>1</sup>	20.73	—	16.75	—	13.00	—	9.36	—	ns
P45	A(0:31), $\overline{\text{REG}}$ valid to ALE negation <sup>1</sup>	28.30	—	23.00	—	18.00	—	13.15	_	ns
P46	CLKOUT to REG valid	7.58	15.58	6.25	14.25	5.00	13.00	3.79	11.84	ns
P47	CLKOUT to REG invalid	8.58	—	7.25	—	6.00	—	4.84	_	ns
P48	CLKOUT to $\overline{CE1}$ , $\overline{CE2}$ asserted	7.58	15.58	6.25	14.25	5.00	13.00	3.79	11.84	ns
P49	CLKOUT to $\overline{CE1}$ , $\overline{CE2}$ negated	7.58	15.58	6.25	14.25	5.00	13.00	3.79	11.84	ns
P50	CLKOUT to PCOE, IORD, PCWE, IOWR assert time	—	11.00		11.00	—	11.00	—	11.00	ns
P51	CLKOUT to PCOE, IORD, PCWE, IOWR negate time	2.00	11.00	2.00	11.00	2.00	11.00	2.00	11.00	ns
P52	CLKOUT to ALE assert time	7.58	15.58	6.25	14.25	5.00	13.00	3.79	10.04	ns
P53	CLKOUT to ALE negate time	—	15.58		14.25	_	13.00	—	11.84	ns
P54	PCWE, IOWR negated to D(0:31) invalid <sup>1</sup>	5.58	—	4.25	—	3.00	—	1.79	—	ns
P55	WAITA and WAITB valid to CLKOUT rising edge <sup>1</sup>	8.00	—	8.00	—	8.00	—	8.00	—	ns
P56	CLKOUT rising edge to WAITA and WAITB invalid <sup>1</sup>	2.00	—	2.00	—	2.00	—	2.00	—	ns

<sup>1</sup> PSST = 1. Otherwise add PSST times cycle time.

PSHT = 0. Otherwise add PSHT times cycle time.

These synchronous timings define when the WAITx signals are detected in order to freeze (or relieve) the PCMCIA current cycle. The WAITx assertion will be effective only if it is detected 2 cycles before the PSL timer expiration. See Chapter 16, "PCMCIA Interface," in the *MPC860 PowerQUICCTM Family User's Manual*.



#### **Bus Signal Timing**

Figure 32 shows the reset timing for the data bus configuration.



Figure 32. Reset Timing—Configuration from Data Bus

Figure 33 provides the reset timing for the data bus weak drive during configuration.



Figure 33. Reset Timing—Data Bus Weak Drive During Configuration





Figure 34 provides the reset timing for the debug port configuration.

Figure 34. Reset Timing—Debug Port Configuration

# **10 IEEE 1149.1 Electrical Specifications**

Table 13 provides the JTAG timings for the MPC860 shown in Figure 35 through Figure 38.

Num	Charactariatia	All Freq	Unit	
Nulli	Characteristic	Min	Мах	Onit
J82	TCK cycle time	100.00	—	ns
J83	TCK clock pulse width measured at 1.5 V	40.00	_	ns
J84	TCK rise and fall times	0.00	10.00	ns
J85	TMS, TDI data setup time	5.00	—	ns
J86	TMS, TDI data hold time	25.00	_	ns
J87	TCK low to TDO data valid	—	27.00	ns
J88	TCK low to TDO data invalid	0.00	—	ns
J89	TCK low to TDO high impedance	—	20.00	ns
J90	TRST assert time	100.00	_	ns
J91	TRST setup time to TCK low	40.00	—	ns
J92	TCK falling edge to output valid	—	50.00	ns
J93	TCK falling edge to output valid out of high impedance	—	50.00	ns
J94	TCK falling edge to output high impedance	—	50.00	ns
J95	Boundary scan input valid to TCK rising edge	50.00	—	ns
J96	TCK rising edge to boundary scan input invalid	50.00		ns

Table 13. JTAG Timing





Figure 43. Parallel I/O Data-In/Data-Out Timing Diagram

# **11.2 Port C Interrupt AC Electrical Specifications**

Table 15 provides the timings for port C interrupts.

Num	Characteristic		$\ge$ 33.34 MHz <sup>1</sup>			
	Unaracteristic	Min	Max	Onit		
35	Port C interrupt pulse width low (edge-triggered mode)	55	—	ns		
36	Port C interrupt minimum time between active edges	55		ns		

<sup>1</sup> External bus frequency of greater than or equal to 33.34 MHz.

Figure 44 shows the port C interrupt detection timing.



Figure 44. Port C Interrupt Detection Timing

# **11.3 IDMA Controller AC Electrical Specifications**

Table 16 provides the IDMA controller timings as shown in Figure 45 through Figure 48.

### Table 16. IDMA Controller Timing

Num	Characteristic	All Freq	Unit	
		Min	Max	Unit
40	DREQ setup time to clock high	7	_	ns
41	DREQ hold time from clock high	3	_	ns





Figure 50. CPM General-Purpose Timers Timing Diagram

# **11.6 Serial Interface AC Electrical Specifications**

Table 19 provides the serial interface timings as shown in Figure 51 through Figure 55.

Num	Obevectovictie	All Frec	11	
NUM	Characteristic	Min	Max	Unit
70	L1RCLK, L1TCLK frequency (DSC = 0) <sup>1, 2</sup>	—	SYNCCLK/2.5	MHz
71	L1RCLK, L1TCLK width low $(DSC = 0)^2$	P + 10	—	ns
71a	L1RCLK, L1TCLK width high $(DSC = 0)^3$	P + 10	—	ns
72	L1TXD, L1ST(1–4), L1RQ, L1CLKO rise/fall time	—	15.00	ns
73	L1RSYNC, L1TSYNC valid to L1CLK edge (SYNC setup time)	20.00	—	ns
74	L1CLK edge to L1RSYNC, L1TSYNC, invalid (SYNC hold time)	35.00	—	ns
75	L1RSYNC, L1TSYNC rise/fall time	—	15.00	ns
76	L1RXD valid to L1CLK edge (L1RXD setup time)	17.00	—	ns
77	L1CLK edge to L1RXD invalid (L1RXD hold time)	13.00	—	ns
78	L1CLK edge to L1ST(1-4) valid <sup>4</sup>	10.00	45.00	ns
78A	L1SYNC valid to L1ST(1-4) valid	10.00	45.00	ns
79	L1CLK edge to L1ST(1-4) invalid	10.00	45.00	ns
80	L1CLK edge to L1TXD valid	10.00	55.00	ns
80A	L1TSYNC valid to L1TXD valid <sup>4</sup>	10.00	55.00	ns
81	L1CLK edge to L1TXD high impedance	0.00	42.00	ns
82	L1RCLK, L1TCLK frequency (DSC =1)	—	16.00 or SYNCCLK/2	MHz
83	L1RCLK, L1TCLK width low (DSC = 1)	P + 10	_	ns
83a	L1RCLK, L1TCLK width high $(DSC = 1)^3$	P + 10	—	ns

### Table 19. SI Timing



**CPM Electrical Characteristics** 







MPC860 PowerQUICC Family Hardware Specifications, Rev. 10



Figure 56 through Figure 58 show the NMSI timings.





Num	Chavastavistia	All Freq	Unit	
	Characteristic	Min	Мах	Onit
135	RSTRT active delay (from TCLK1 falling edge)	10	50	ns
136	RSTRT inactive delay (from TCLK1 falling edge)	10	50	ns
137	REJECT width low	1	—	CLK
138	CLKO1 low to SDACK asserted <sup>2</sup>		20	ns
139	CLKO1 low to SDACK negated <sup>2</sup>	_	20	ns

### Table 22. Ethernet Timing (continued)

<sup>1</sup> The ratios SYNCCLK/RCLK1 and SYNCCLK/TCLK1 must be greater than or equal to 2/1.

<sup>2</sup> SDACK is asserted whenever the SDMA writes the incoming frame DA into memory.



Figure 59. Ethernet Collision Timing Diagram



Figure 60. Ethernet Receive Timing Diagram



#### **SMC Transparent AC Electrical Specifications** 11.9

Table 23 provides the SMC transparent timings as shown in Figure 64.

### Table 23. SMC Transparent Timing

Num	Chavastavistia	All Freq	llmit	
	Characteristic	Min	Мах	Unit
150	SMCLK clock period <sup>1</sup>	100	—	ns
151	SMCLK width low	50	—	ns
151A	SMCLK width high	50	—	ns
152	SMCLK rise/fall time	—	15	ns
153	SMTXD active delay (from SMCLK falling edge)	10	50	ns
154	SMRXD/SMSYNC setup time	20	—	ns
155	RXD1/SMSYNC hold time	5	—	ns

<sup>1</sup> SYNCCLK must be at least twice as fast as SMCLK.



Note: 1. This delay is equal to an integer number of character-length clocks.





Figure 69 shows the  $I^2C$  bus timing.



Figure 69. I<sup>2</sup>C Bus Timing Diagram

# **12 UTOPIA AC Electrical Specifications**

Table 28 shows the AC electrical specifications for the UTOPIA interface.

Num	Signal Characteristic	Direction	Min	Max	Unit
U1	UtpClk rise/fall time (Internal clock option)	Output	_	3.5	ns
	Duty cycle		50	50	%
	Frequency		_	50	MHz
U1a	UtpClk rise/fall time (external clock option)	Input	_	3.5	ns
	Duty cycle		40	60	%
	Frequency		_	50	MHz
U2	RxEnb and TxEnb active delay	Output	2	16	ns
U3	UTPB, SOC, Rxclav and Txclav setup time	Input	8	—	ns
U4	UTPB, SOC, Rxclav and Txclav hold time	Input	1	—	ns
U5	UTPB, SOC active delay (and PHREQ and PHSEL active delay in MPHY mode)	Output	2	16	ns

### Table 28. UTOPIA AC Electrical Specifications



# Table 34 identifies the packages and operating frequencies available for the MPC860.

Package Type	Freq. (MHz) / Temp. (Tj)	Package	Order Number
Ball grid array ZP suffix—leaded ZQ suffix—lead-free VR suffix—lead-free	50 0° to 95°C	ZP/ZQ <sup>1</sup>	MPC855TZQ50D4 MPC860DEZQ50D4 MPC860DTZQ50D4 MPC860ENZQ50D4 MPC860SRZQ50D4 MPC860TZQ50D4 MPC860DPZQ50D4 MPC860PZQ50D4
		Tape and Reel	MPC855TZQ50D4R2 MPC860DEZQ50D4R2 MPC860ENZQ50D4R2 MPC860SRZQ50D4R2 MPC860TZQ50D4R2 MPC860DPZQ50D4R2 MPC855TVR50D4R2 MPC860ENVR50D4R2 MPC860SRVR50D4R2 MPC860TVR50D4R2
		VR	MPC855TVR50D4 MPC860DEVR50D4 MPC860DPVR50D4 MPC860DTVR50D4 MPC860ENVR50D4 MPC860PVR50D4 MPC860SRVR50D4 MPC860SRVR50D4 MPC860TVR50D4
	66 0° to 95°C	ZP/ZQ <sup>1</sup>	MPC855TZQ66D4 MPC860DEZQ66D4 MPC860DTZQ66D4 MPC860ENZQ66D4 MPC860SRZQ66D4 MPC860TZQ66D4 MPC860DPZQ66D4 MPC860PZQ66D4
		Tape and Reel	MPC860SRZQ66D4R2 MPC860PZQ66D4R2
		VR	MPC855TVR66D4 MPC860DEVR66D4 MPC860DPVR66D4 MPC860DTVR66D4 MPC860ENVR66D4 MPC860PVR66D4 MPC860SRVR66D4 MPC860TVR66D4

# Table 34. MPC860 Family Package/Frequency Availability